

Features

- Operation Voltage Range: 1.65~5.5V
- Inputs Accept Voltages to 5.5V
- Max tPD of 0.8 ns at 3.3V
- High Degree of Linearity
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

General Description

The **74LVC1G66** is a high-speed CMOS device.

The **74LVC1G66** has two data input/output pins

(A and B) and an active HIGH enable input pin(C) .

The **74LVC1G66** can handle both analog and

digital signals. The signals can be transmitted in

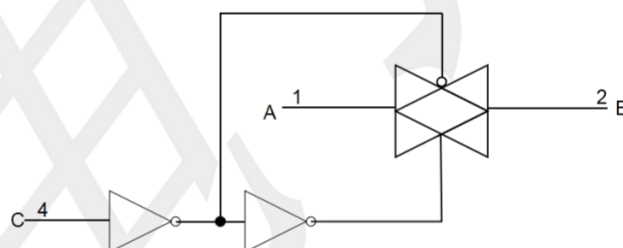
either direction when enable pin is high . The analog

switch is off when enable pin is low.

Applications

- Wireless Devices
- Audio and Video Signal Routing
- Portable Computing
- Wearable Devices
- Signal Gating, Chopping, Modulation or Demodulation (Modem)
- Signal Multiplexing for Analog-to-Digital and Digital-to-Analog Conversion Systems

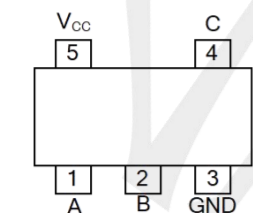
Logic Diagram



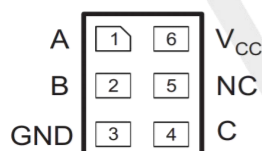
Ordering Information

ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION
TP74LVC1G66S5	SOT23-5	Tape and Reel,3000
TP74LVC1G66C5	SOT353	Tape and Reel,3000
TP74LVC1G66X5	SOT553	Tape and Reel,4000
TP74LVC1G66D6	DFN1X1-6	Tape and Reel,5000
TP74LVC1G66N6	DFN1510-6	Tape and Reel,5000

Pin Configuration



SOT23-5
SOT353
SOT553



DFN1X1-6
DFN1510-6

Function Table(each gate)

CONTROL INPUT(C)	SWITCH
L	OFF
H	ON

Absolute Maximum Ratings

($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage(Note2)	V_{CC}	-0.5 ~ 6.5	V
Input Voltage	V_{IN}	-0.5 ~ 6.5	V
Switch I/O Voltage Range	$V_{I/O}$	-0.5 ~ $V_{CC}+0.5$	V
Control Input Clamp Current($V_{IN}<0$)	I_{IK}	-50	mA
I/O Port Diode Current ($V_{I/O}<0$ or $V_{I/O}>V_{CC}$)	I_{IOK}	± 50	mA
On-state Switch Current ($V_{I/O}: 0$ to V_{CC})	I_T	± 50	mA
V_{CC} or GND Current	I_{CC}	± 100	mA
Storage Temperature	T_{STG}	-65 ~ +150	$^{\circ}\text{C}$

Notes: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Recommended Operating Conditions

($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}		1.65	--	5.5	V
Input Voltage	V_{IN}		0	--	5.5	V
I/O Port Voltage	$V_{I/O}$		0	--	V_{CC}	V
Input Transition Rise/Fall Time	t_R / t_F	$V_{CC}=1.65\text{V}\sim 1.95\text{V}$	--	--	20	ns
		$V_{CC}=2.3\text{V}\sim 2.7\text{V}$	--	--	20	ns
		$V_{CC}=3\text{V}\sim 3.6\text{V}$	--	--	10	ns
		$V_{CC}=4.5\text{V}\sim 5.5\text{V}$	--	--	10	ns
Operating Temperature	T_A		-40	--	+125	$^{\circ}\text{C}$

STATIC CHARACTERISTICS (Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A =25°C			T _A =-40°C~+125°C			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
High-level Input Voltage	V _{IH}	V _{CC} =1.65V~1.95V		0.65× V _{CC}	--	--	0.65× V _{CC}	--	--	V
		V _{CC} =2.3V~2.7V		1.7	--	--	1.7	--	--	V
		V _{CC} =3V ~3.6V		2	--	--	2	--	--	V
		V _{CC} =4.5V~5.5V		0.7× V _{CC}	--	--	0.7× V _{CC}	--	--	V
Low-level Input Voltage	V _{IL}	V _{CC} =1.65V~1.95V		--	--	0.35 × V _{CC}	--	--	0.35× V _{CC}	V
		V _{CC} =2.3V~2.7V		--	--	0.7	--	--	0.7	V
		V _{CC} =3V~3.6V		--	--	0.8	--	--	0.8	V
		V _{CC} =4.5V~5.5V		--	--	0.3 × V _{CC}	--	--	0.3× V _{CC}	V
ON-Resistance (Rail)	R _{ON(rail)}	V _I =GND or V _{CC}	V _{CC} =1.65V, I _S =4mA	--	12	30	--	--	45	Ω
			V _{CC} =2.3V, I _S =8mA	--	9	20	--	--	30	Ω
			V _{CC} =3V, I _S =24mA	--	7.5	15	--	--	23	Ω
			V _{CC} =4.5V, I _S =32mA	--	5.5	10	--	--	15	Ω
ON-Resistance (Peak)	R _{ON(peak)})	V _I =GND to V _{CC}	V _{CC} =1.65V, I _S =4mA	--	105	140	--	--	185	Ω
			V _{CC} =2.3V, I _S =8mA	--	30	40	--	--	50	Ω
			V _{CC} =3V, I _S =24mA	--	11.5	20	--	--	30	Ω
			V _{CC} =4.5V, I _S =32mA	--	7.5	15	--	--	23	Ω
On-state Switch Leakage Current	I _{S(ON)}	V _I = V _{CC} or GND, V _C = V _{IH} , V _O = Open, V _{CC} =5.5V		--	--	±0.1	--	--	2	μA
Off-state Switch Leakage Current	I _{S(off)}	V _I = V _{CC} and V _O = GND or V _I = GND and V _O = V _{CC} , V _C = V _{IL} , V _{CC} =5.5V		--	--	±0.1	--	--	1	μA
Control Input Current	I _{I(CTL)}	V _C = V _{CC} or GND, V _{CC} =5.5V		--	--	±0.1	--	--	1	μA
Quiescent Supply Current	I _{CC}	V _C = V _{CC} or GND, V _{CC} =5.5V		--	--	1	--	--	10	μA
Additional Quiescent Supply Current	ΔI _{CC}	V _C = V _{CC} -0.6V, V _{CC} =5.5V		--	--	500	--	--	500	μA

ANALOG SWITCH CHARACTERISTICS

(T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Frequency Response From Input (A or B) to Output (B or A) (Note 1) (Switch ON)	f _{MAX}	C _L =50pF, R _L =600Ω, F _{IN} =Wine Wave	V _{CC} =1.65V	--	35	--	MHz
			V _{CC} =2.3	--	120	--	MHz
			V _{CC} =3V	--	175	--	MHz
			V _{CC} =4.5V	--	195	--	MHz
		C _L =5pF, R _L =50Ω, F _{IN} =Sine Wave	V _{CC} =1.65V	--	>300	--	MHz
			V _{CC} =2.3V	--	>300	--	MHz
			V _{CC} =3V	--	>300	--	MHz
			V _{CC} =4.5V	--	>300	--	MHz
Crosstalk Voltage From Input (C) to Output (A or B) (Control Input to Signal Output)	V _{CT}	C _L =50pF, R _L =600Ω, F _{IN} =1MHZ (Square Wave)	V _{CC} =1.65V	--	35	--	mV
			V _{CC} =2.3V	--	50	--	mV
			V _{CC} =3V	--	70	--	mV
			V _{CC} =4.5V	--	100	--	mV
Feedthrough Attenuation From Input (A or B) to Output (B or A) (Note 2) (Switch OFF)	α _{iso}	C _L =50pF, R _L =600Ω, F _{IN} =1MHZ (Square Wave)	V _{CC} =1.65V	--	-58	--	dB
			V _{CC} =2.3V	--	-58	--	dB
			V _{CC} =3V	--	-58	--	dB
			V _{CC} =4.5V	--	-58	--	dB
		C _L =5pF, R _L =50Ω, F _{IN} =1MHZ (Square Wave)	V _{CC} =1.65V	--	-42	--	dB
			V _{CC} =2.3V	--	-42	--	dB
			V _{CC} =3V	--	-42	--	dB
			V _{CC} =4.5V	--	-42	--	dB
Sine-Wave Distortion From Input (A or B) to Output (B or A)	THD	C _L =50pF, R _L =10KΩ, F _{IN} =1KHZ (Square Wave)	V _{CC} =1.65V	--	0.1	--	%
			V _{CC} =2.3V	--	0.025	--	%
			V _{CC} =3V	--	0.015	--	%
			V _{CC} =4.5V	--	0.01	--	%
		C _L =50pF, R _L =10kΩ, F _{IN} =10KHz (Square Wave)	V _{CC} =1.65V	--	0.15	--	%
			V _{CC} =2.3V	--	0.025	--	%
			V _{CC} =3V	--	0.015	--	%
			V _{CC} =4.5V	--	0.01	--	%

Notes: 1. Adjust f_{IN} voltage to obtain 0 dBm at output. Increase f_{IN} frequency until dB meter reads -3dB.

2. Adjust f_{IN} voltage to obtain 0 dBm at input.

DYNAMIC CHARACTERISTICS

(Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A =25°C			T _A =-40°C~+125°C			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
Propagation Delay From Input (A or B) to Output (B or A)	t _{PD} (Note 1)	V _{CC} =1.8V±0.15V	--	--	3	--	--	4	ns
		V _{CC} =2.5V±0.2V	--	--	2.4	--	--	3.4	ns
		V _{CC} =3.3V±0.3V	--	--	2.2	--	--	3.2	ns
		V _{CC} =5V±0.5V	--	--	2	--	--	3	ns
Enable Time From Input (C) to Output (A or B)	t _{EN} (Note 2)	V _{CC} =1.8V±0.15V	1.0	--	12	--	--	15.5	ns
		V _{CC} =2.5V±0.2V	1.0	--	7.5	--	--	9.5	ns
		V _{CC} =3.3V±0.3V	1.0	--	6.5	--	--	8	ns
		V _{CC} =5V±0.5V	1.0	--	5.5	--	--	6.5	ns
Disable Time From Input (C) to Output (A or B)	t _{DIS} (Note 3)	V _{CC} =1.8V±0.15V	1.0	--	10	--	--	13	ns
		V _{CC} =2.5V±0.2V	1.0	--	6.9	--	--	9	ns
		V _{CC} =3.3V±0.3V	1.0	--	6.5	--	--	8.5	ns
		V _{CC} =5V±0.5V	1.0	--	5	--	--	6.5	ns

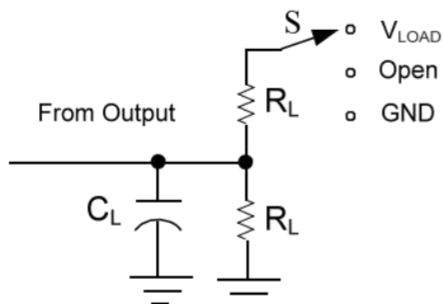
Notes: 1. t_{PLH} and t_{PHL} are the same as t_{PD}.
2. t_{PZL} and t_{PHZ} are the same as t_{EN}.
3. t_{PLZ} and t_{PHZ} are the same as t_{DIS}.

OPERATING CHARACTERISTICS

(T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Cic Control input Capacitance	C _{IC}	V _{CC} =5V	--	2	--	pF
C _{IO(OFF)} Switch Input/Output Capacitance	C _{OFF}	V _{CC} =5V	--	6	--	pF
C _{IO(ON)} Switch Input/Output Capacitance	C _{ON}	V _{CC} =5V	--	13	--	pF
Power Dissipation Capacitance	C _{PD}	V _{CC} =3.3V, f=10MHz	--	9	--	pF

TEST CIRCUIT AND WAVEFORMS



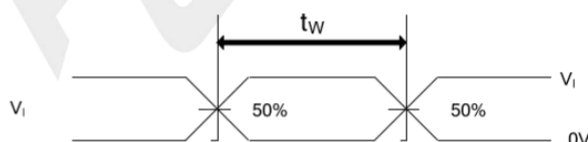
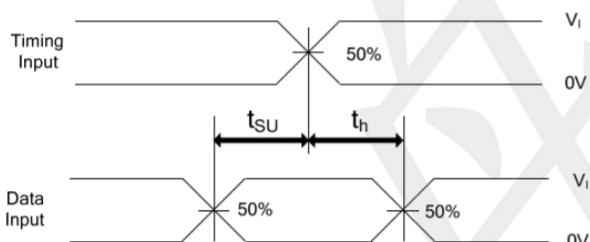
TEST	S
t_{PLH}/t_{PHL}	Open
t_{PHZ}/t_{PZH}	GND
t_{PLZ}/t_{PZL}	V_{LOAD}

t_{PD} is the same as t_{PHL} and t_{PLH} .
 t_{en} is the same as t_{PZL} and t_{PZH} .
 t_{dis} is the same as t_{PLZ} and t_{PHZ} .

TEST CIRCUIT

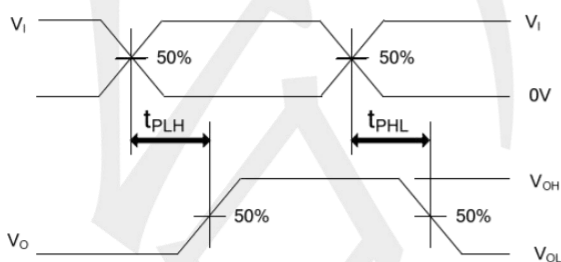
Note: C_L includes probe and jig capacitance.

V_{CC}	V_I	t_R, t_F	V_M	V_{LOAD}	C_L	R_L	V_{Δ}
1.65V~1.95V	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	30pF	1k Ω	0.15V
2.3V~2.7V	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	30pF	500 Ω	0.15V
3.0V~3.6V	V_{CC}	$\leq 2.5ns$	$V_{CC}/2$	$2 \times V_{CC}$	50pF	500 Ω	0.3V
4.5V~5.5V	V_{CC}	$\leq 2.5ns$	$V_{CC}/2$	$2 \times V_{CC}$	50pF	500 Ω	0.3V

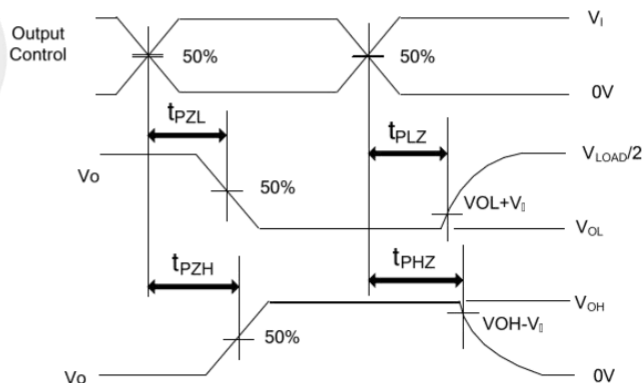


PULSE WIDTH

SETUP TIME AND HOLD TIME



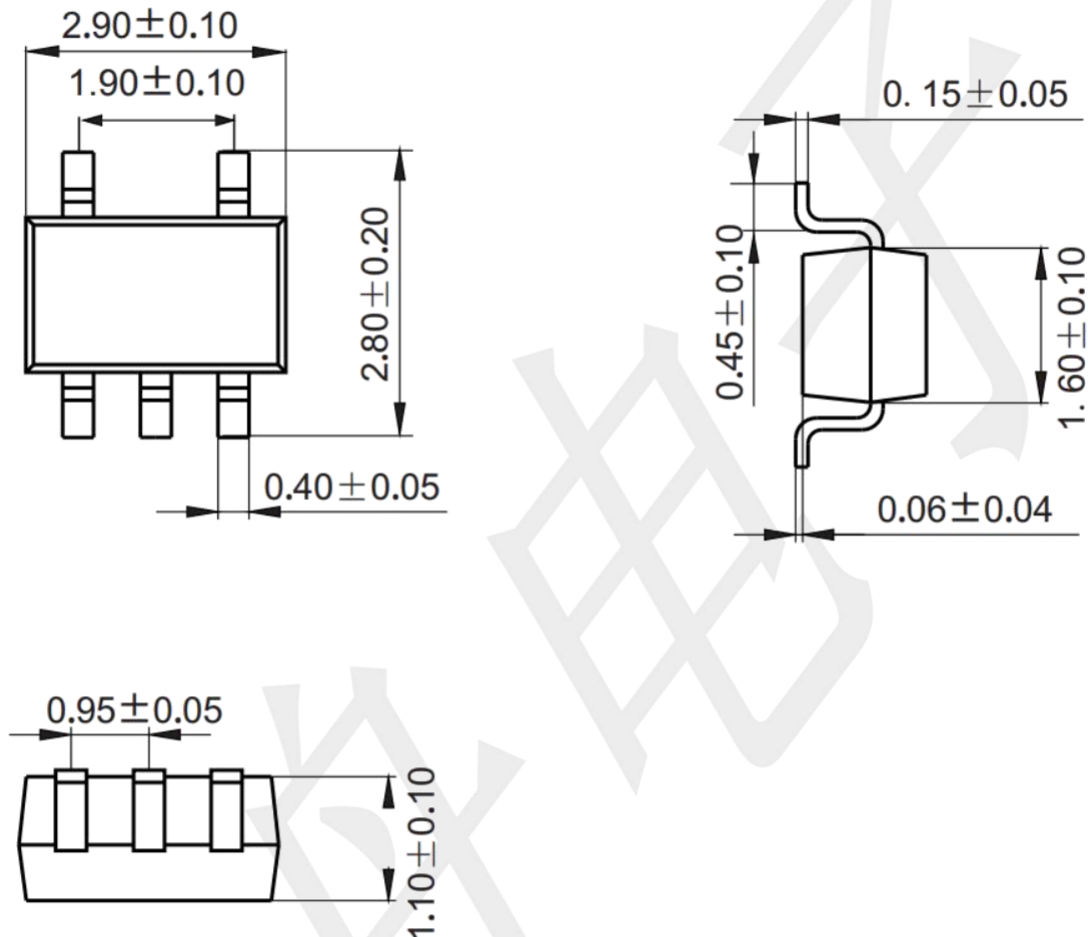
PROPAGATION DELAY TIMES



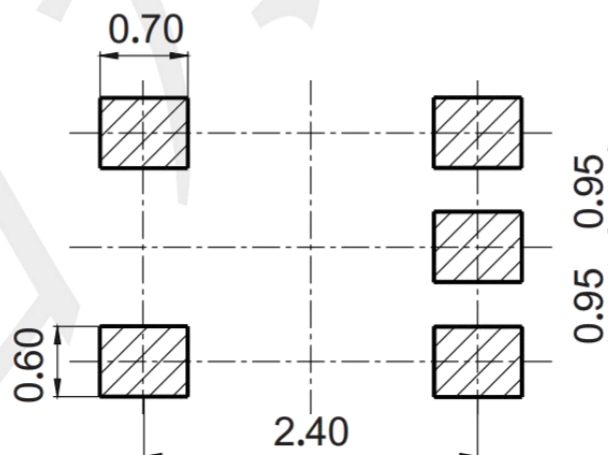
ENABLE AND DISABLE TIMES

Package informantion

SOT23-5 (Unit: mm)

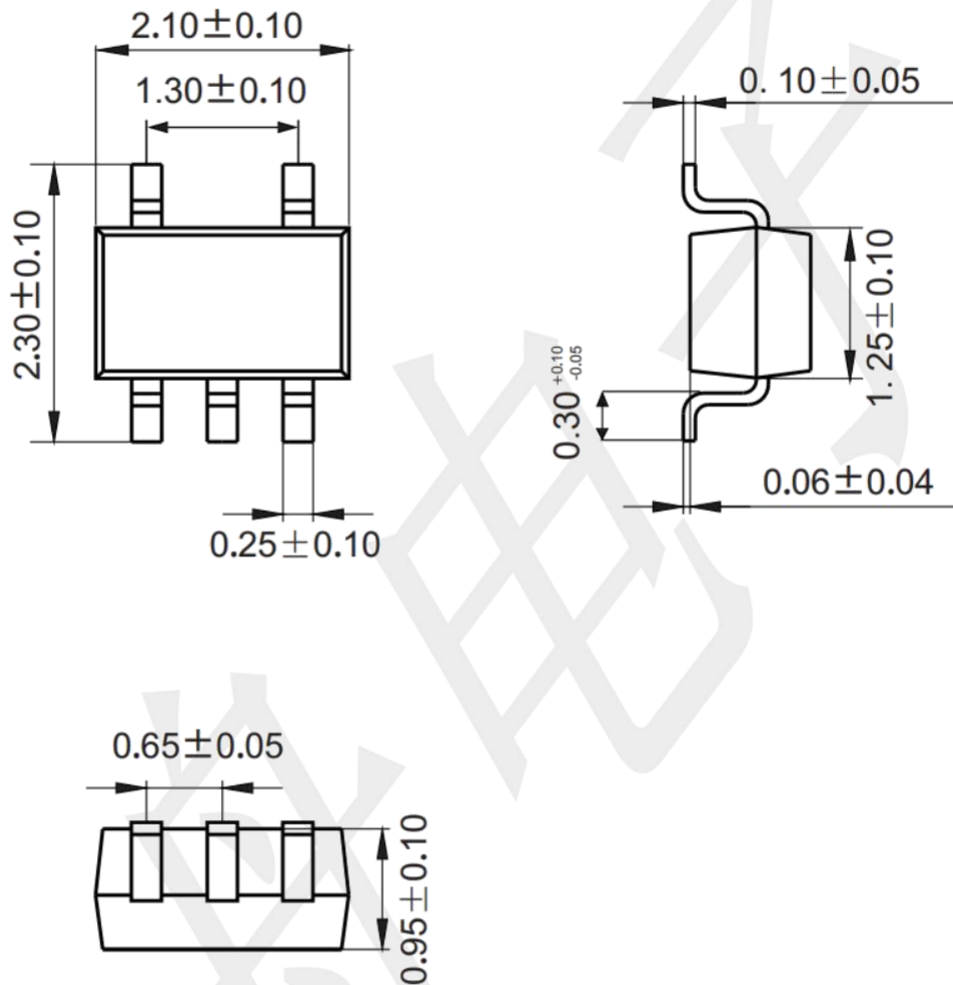


Mounting Pad Layout (Unit: mm)

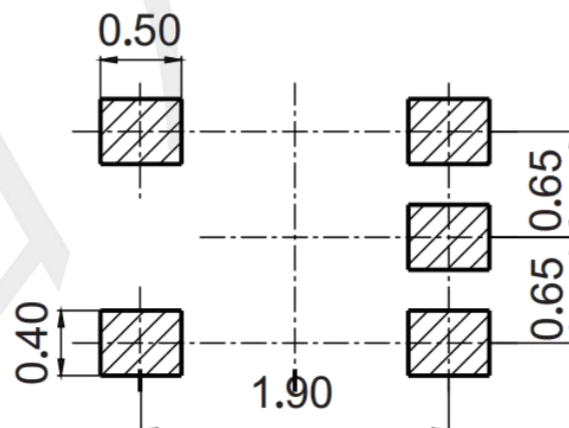


Package informantion

SOT353 (Unit: mm)

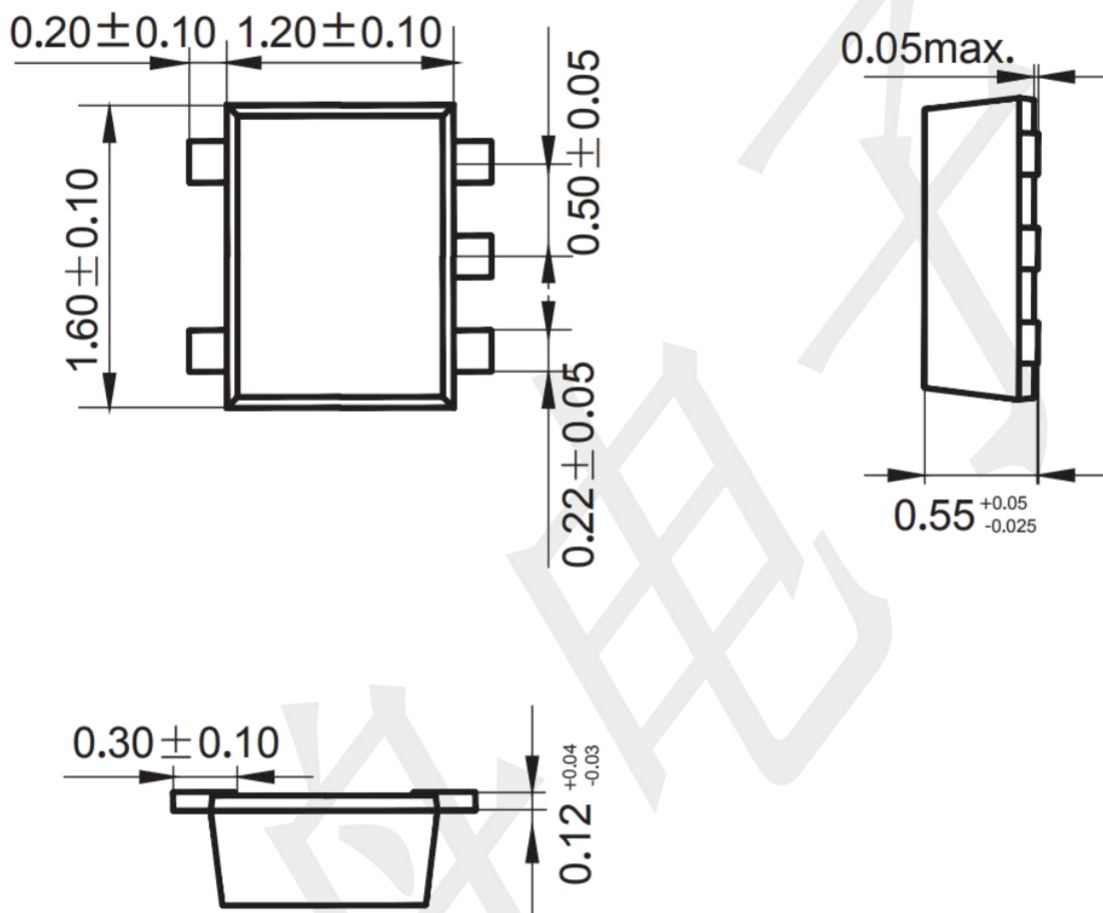


Mounting Pad Layout (Unit: mm)

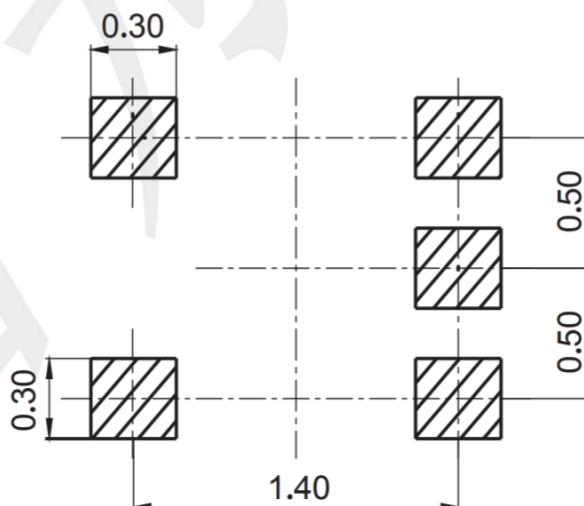


Package informantion

SOT553 (unit: mm)

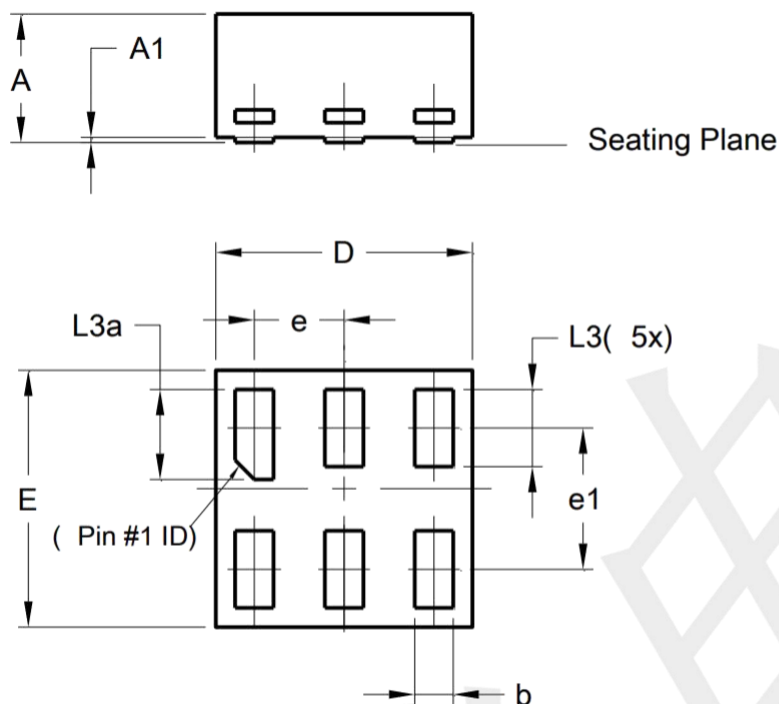


Mounting Pad Layout (unit: mm)



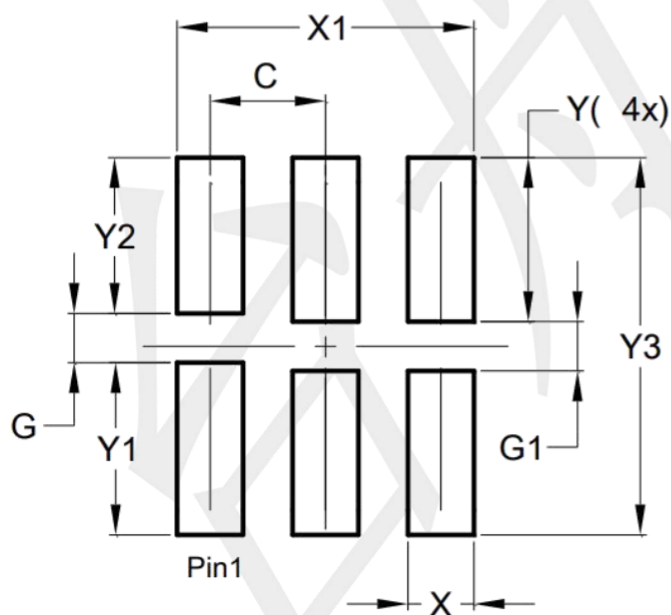
Package informantion

DFN1X1-6 (unit: mm)



DFN1010-6 (Type B)			
Dim	Min	Max	Typ
A	-	0.50	0.39
A1	-	0.04	-
b	0.12	0.20	0.15
D	0.95	1.050	1.00
E	0.95	1.050	1.00
e	0.35 BSC		
e1	0.55 BSC		
L3	0.27	0.30	0.30
L3a	0.32	0.40	0.35
All Dimensions in mm			

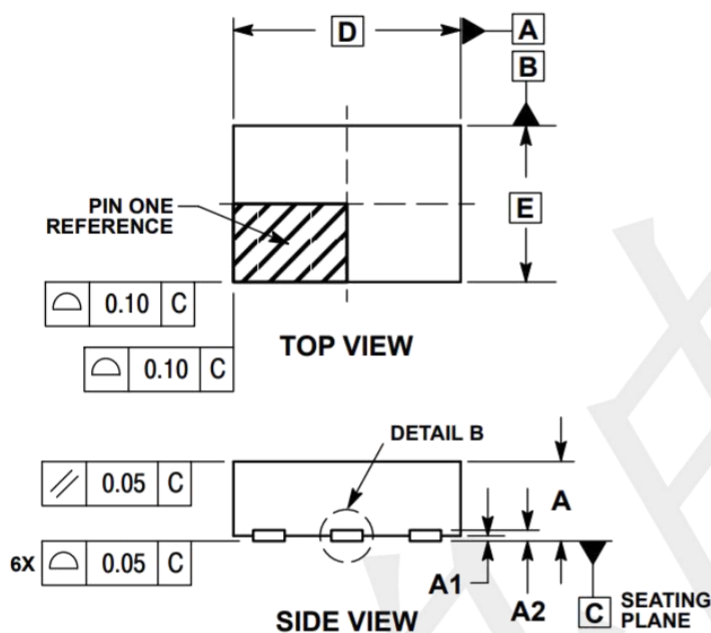
Mounting Pad Layout (unit: mm)



Dimensions	Value (in mm)
C	0.350
G	0.150
G1	0.150
X	0.200
X1	0.900
Y	0.500
Y1	0.525
Y2	0.475
Y3	1.150

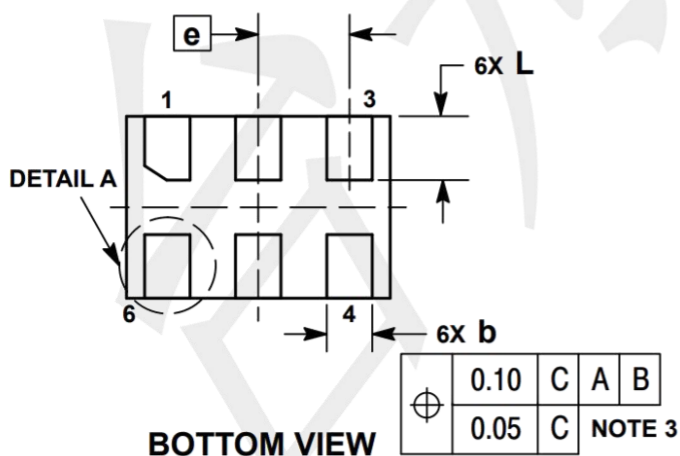
Package informantion

DFN1510-6 (unit: mm)



DIM	MILLIMETERS	
	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A2	0.07 REF	
b	0.20	0.30
D	1.45 BSC	
E	1.00 BSC	
e	0.50 BSC	
L	0.30	0.40
L1	---	0.15

Mounting Pad Layout (unit: mm)



MOUNTING FOOTPRINT

